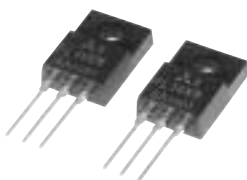


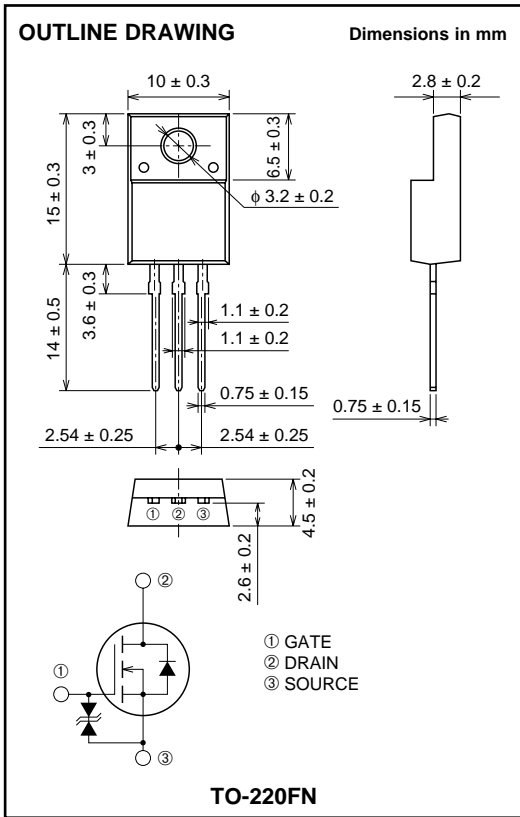
# FL16KM-6A

HIGH-SPEED SWITCHING USE

**FL16KM-6A**



- 10V DRIVE
- V<sub>DSS</sub> ..... 300V
- r<sub>DS (ON)</sub> (MAX) ..... 0.35Ω
- I<sub>D</sub> ..... 16A



## APPLICATION

SMPS, Inverter fluorescent light sets, etc.

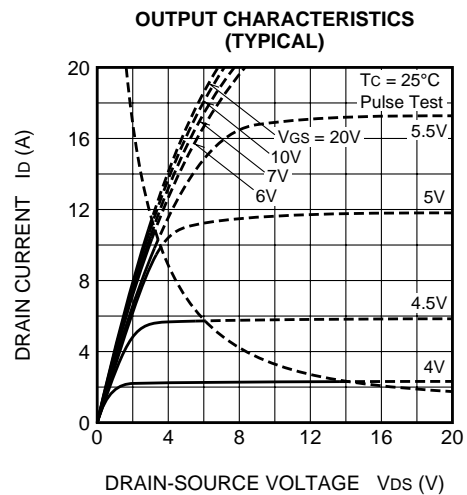
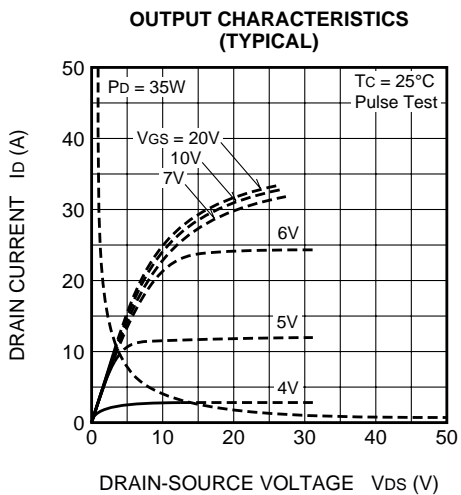
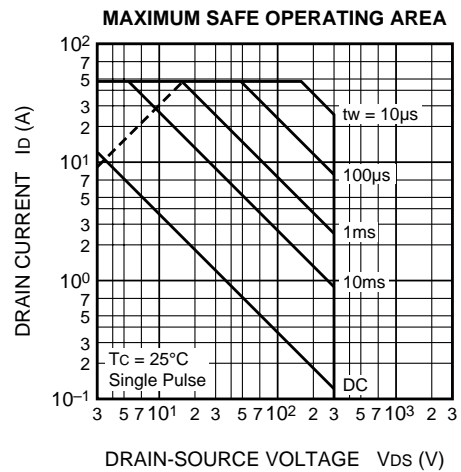
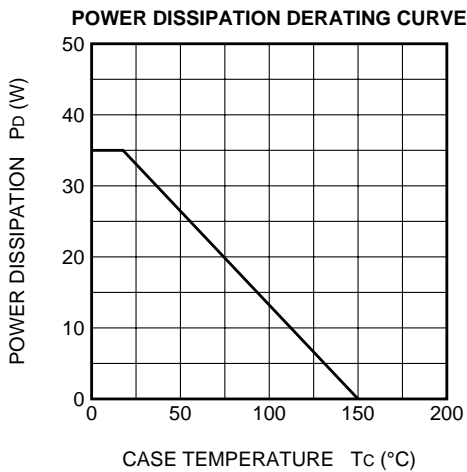
## MAXIMUM RATINGS (T<sub>c</sub> = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V <sub>DSS</sub>	Drain-source voltage	V <sub>GS</sub> = 0V	300	V
V <sub>GSS</sub>	Gate-source voltage	V <sub>DS</sub> = 0V	±30	V
I <sub>D</sub>	Drain current		16	A
I <sub>DM</sub>	Drain current (Pulsed)		48	A
I <sub>DA</sub>	Avalanche drain current (Pulsed)	L = 200μH	16	A
P <sub>D</sub>	Maximum power dissipation		35	W
T <sub>ch</sub>	Channel temperature		-55 ~ +150	°C
T <sub>stg</sub>	Storage temperature		-55 ~ +150	°C
V <sub>iso</sub>	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

**ELECTRICAL CHARACTERISTICS** (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	ID = 1mA, VGS = 0V	300	—	—	V
V (BR) GSS	Gate-source breakdown voltage	IGS = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate-source leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IDSS	Drain-source leakage current	VDS = 300V, VGS = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	ID = 1mA, VDS = 10V	2.0	3.0	4.0	V
rDS (ON)	Drain-source on-state resistance	ID = 8A, VGS = 10V	—	0.29	0.35	Ω
VDS (ON)	Drain-source on-state voltage	ID = 8A, VGS = 10V	—	2.32	2.80	V
yfs	Forward transfer admittance	ID = 8A, VDS = 10V	—	10	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	950	—	pF
Coss	Output capacitance		—	175	—	pF
Crss	Reverse transfer capacitance		—	20	—	pF
td (on)	Turn-on delay time	VDD = 150V, ID = 8A, VGS = 10V, RGEN = RGS = 50Ω	—	15	—	ns
tr	Rise time		—	30	—	ns
td (off)	Turn-off delay time		—	150	—	ns
tf	Fall time		—	60	—	ns
VSD	Source-drain voltage	IS = 8A, VGS = 0V	—	1.5	2.0	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	3.57	°C/W

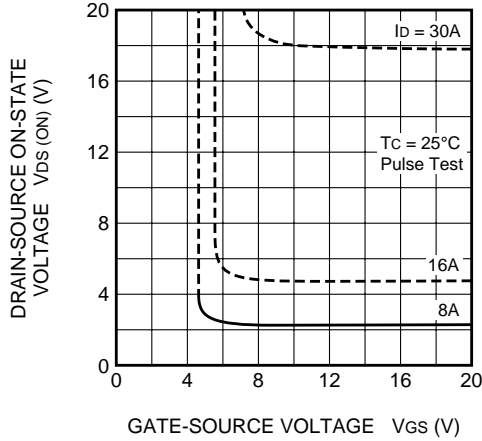
**PERFORMANCE CURVES**



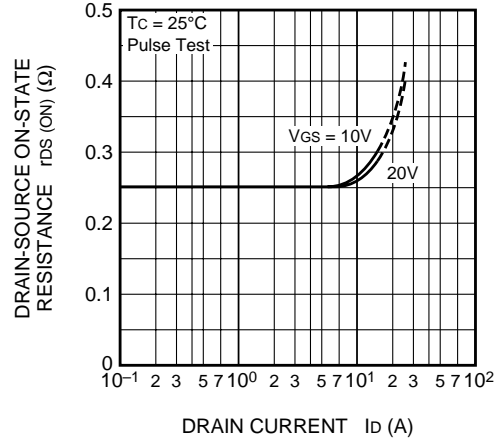
# FL16KM-6A

## HIGH-SPEED SWITCHING USE

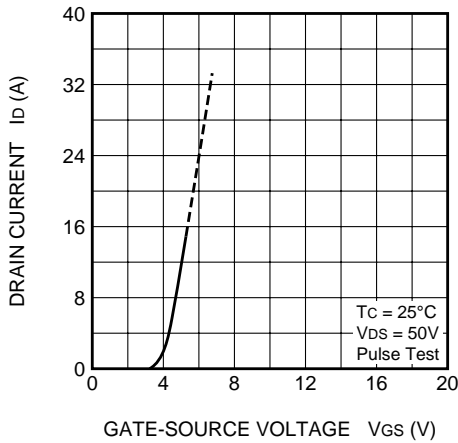
**ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)**



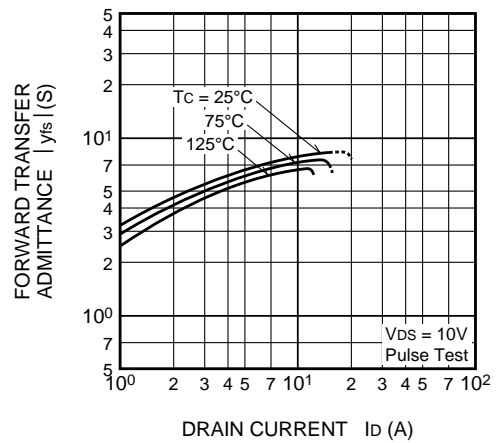
**ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)**



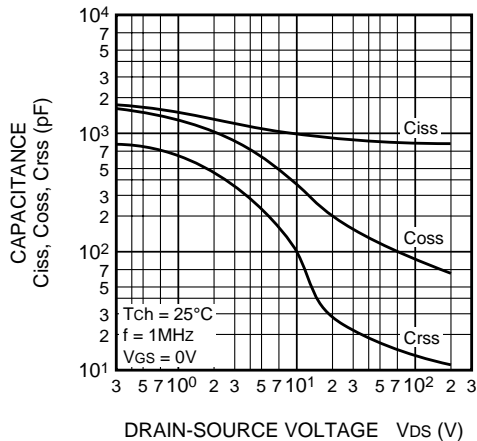
**TRANSFER CHARACTERISTICS (TYPICAL)**



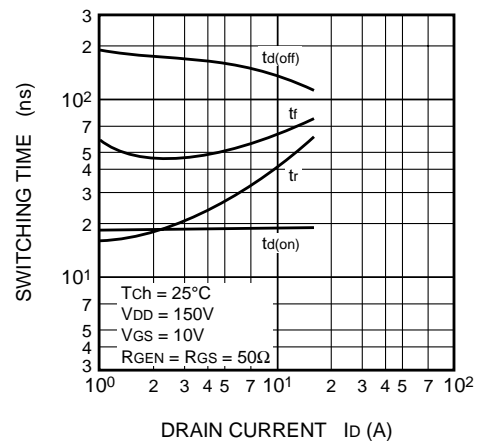
**FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)**



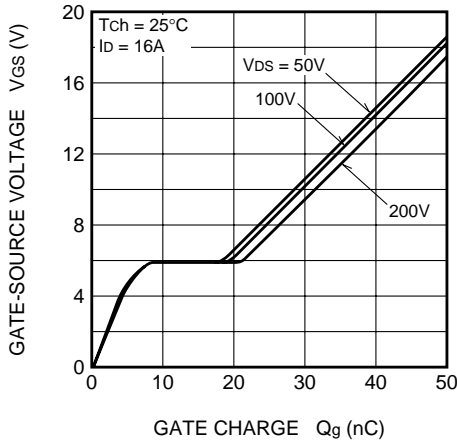
**CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)**



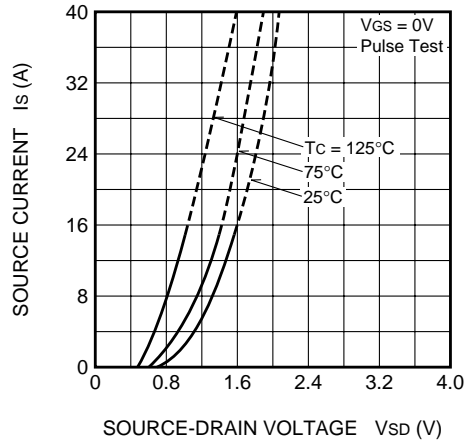
**SWITCHING CHARACTERISTICS (TYPICAL)**



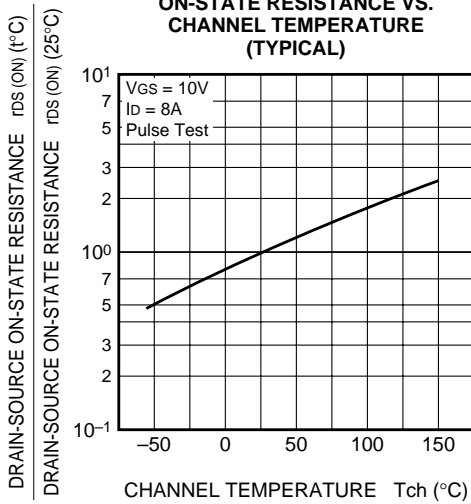
GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)



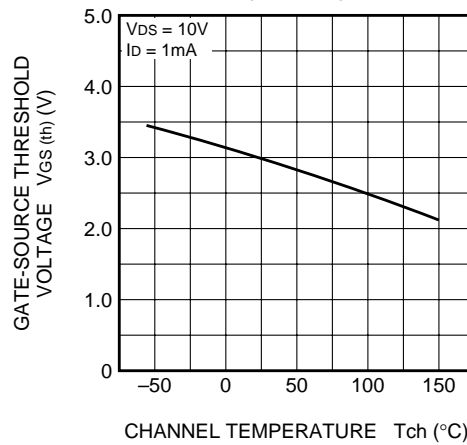
SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)



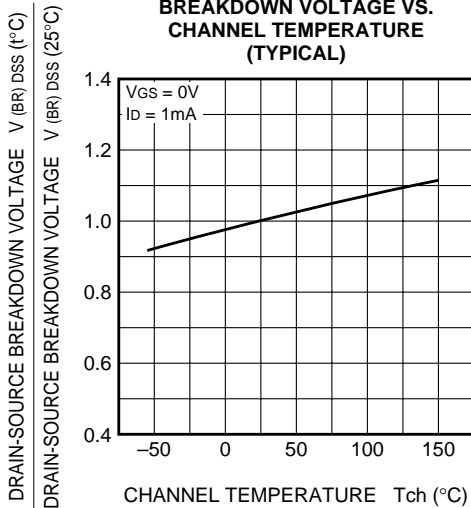
ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)



THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



BREAKDOWN VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS

